

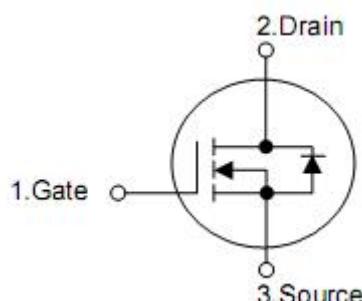
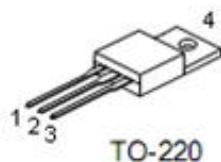
1. Features

- RDS(ON)= 10mΩ(typ.)@ VGS=10V
- Uses CRM(CQ) advanced Trench technology
- Extremely low on-resistance RDS(on)
- Excellent QgxRDS(on) product(FOM)
- Qualified according to JEDEC criteria

2. Application

- Motor control and drive
- Battery management
- UPS (Uninterruptible Power Supplies)

3. Pin configuration



Pin	Function
1	Gate
2	Drain
3	Source
4	Drain

4. Ordering Information

Part Number	Package	Brand
KNP2915A	TO-220	KIA

5. Absolute maximum ratings

TC=25 °C unless otherwise specified

Parameter	Symbol	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}	150	V
Continuous Drain Current T _C =25 °C(Silicon limited)	I _D	130	A
		160	
		80	
Pulsed drain current (T _C = 25°C, t _p limited by T _{jmax})	I _{DP}	500	
Avalanche energy, single pulse (L=0.5mH, R _g =25Ω)	E _{AS}	272	mJ
Gate-Source voltage	V _{GS}	±25	V
Power dissipation (TC = 25 °C)	P _{tot}	428	W
Junction & Storage Temperature Range	T _J & T _{STG}	-55 to 150	°C

6. Thermal characteristics

Parameter	Symbol	Ratings	Units
Thermal resistance, junction-ambient	R _{θJA}	0.29	°C/W
Thermal resistance, Junction-case	R _{θJC}	65	

7. Electrical characteristics

($T_J=25^\circ\text{C}$, unless otherwise notes)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	150	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=150\text{V}, V_{\text{GS}}=0\text{V}, T_j=25^\circ\text{C}$	-	0.05	1	μA
		$V_{\text{DS}}=150\text{V}, V_{\text{GS}}=0\text{V}, T_j=150^\circ\text{C}$	-	-	20	
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	3	4	5	V
Gate leakage current	I_{GSS}	$V_{\text{GS}}=25\text{V}, V_{\text{DS}}=0\text{V}$	-	10	100	nA
Drain-source on-resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=50\text{A}, T_j=25^\circ\text{C}$	-	10	15	$\text{m}\Omega$
		$V_{\text{DS}}=4.5\text{V}, I_{\text{D}}=25\text{A}, T_j=150^\circ\text{C}$	-	22	27	
Forward Transconductance	g_{fs}	$V_{\text{DS}}=5\text{V}, I_{\text{D}}=50\text{A}$	-	100	-	S
Dynamic characteristics						
Gate Resistance	R_G	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=0\text{V}$ Frequency=1MHz	-	1.5	-	Ω
Input capacitance	C_{iss}	$V_{\text{DS}}=0\text{V}, V_{\text{GS}}=75\text{V},$ $F=1\text{MHz}$	-	3560	-	pF
Output capacitance	C_{oss}		-	330	-	pF
Reverse transfer capacitance	C_{rss}		-	90	-	pF
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=75\text{V}, I_{\text{D}}=50\text{A},$ $V_{\text{GS}}=10\text{V}, R_G=2.7\Omega$	-	18	-	ns
Rise time	t_r		-	92	-	ns
Turn-off delay time	$t_{\text{d}(\text{off})}$		-	35	-	ns
Fall time	t_f		-	70	-	ns
Gate Charge Characteristics						
Total gate charge	Q_g	$V_{\text{DS}}=75\text{V}, I_{\text{D}}=50\text{A},$ $V_{\text{GS}}=10\text{V}, F=1\text{MHz}$	-	70	-	nC
Gate-source charge	Q_{gs}		-	24	-	nC
Gate-drain charge	Q_{gd}		-	25	-	nC
Diode characteristics						
Diode forward voltage	V_{SD}	$V_{\text{GS}}=0\text{V}, I_{\text{SD}}=30\text{A}$	-	-	1.3	V
Reverse recovery time	t_{rr}	$I_F=50\text{A}$ $DI_F/dt=100\text{A}/\mu\text{s}$	-	70	-	ns
Reverse recovery charge	Q_{rr}		-	233	-	nC

8. Typical Characteristics

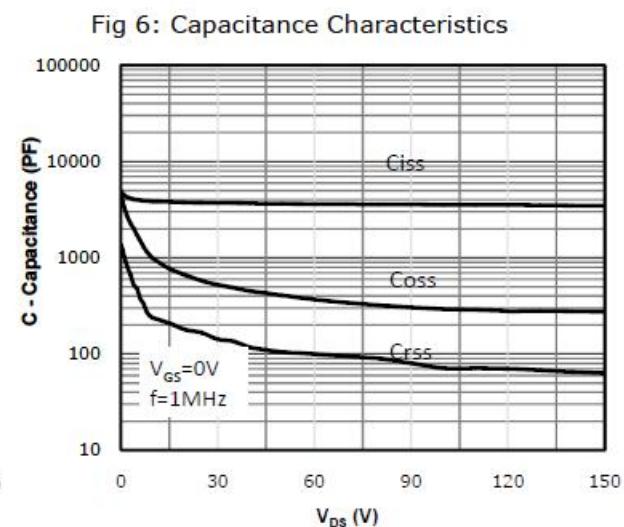
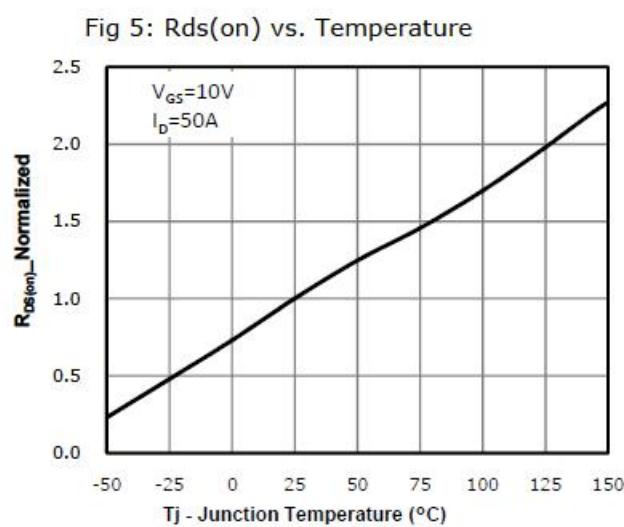
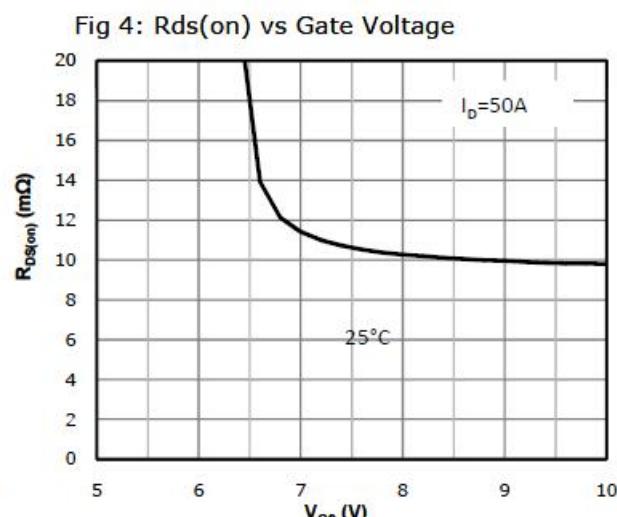
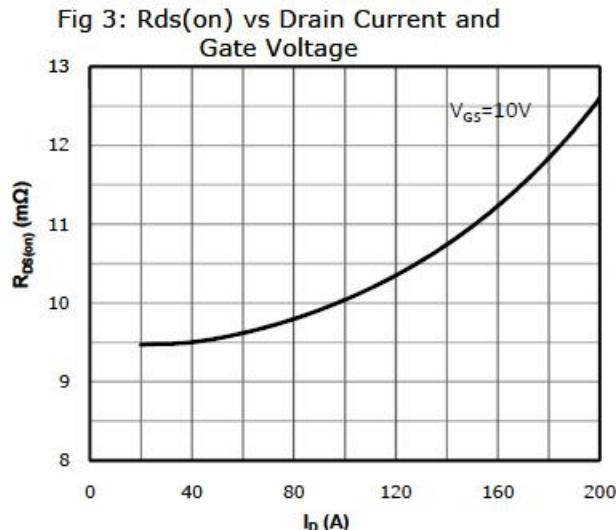
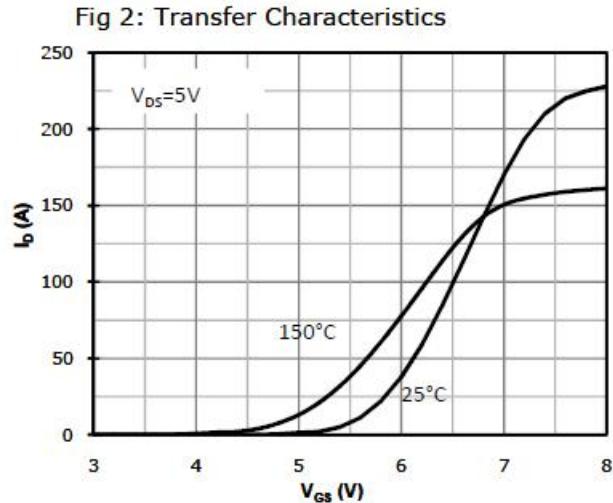
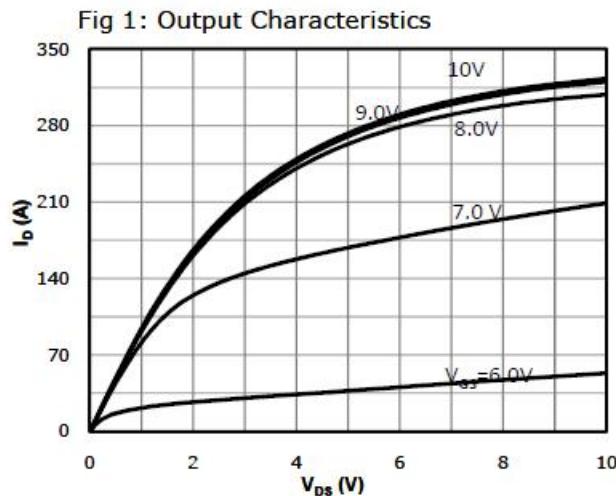


Fig 7: Gate Charge Characteristics

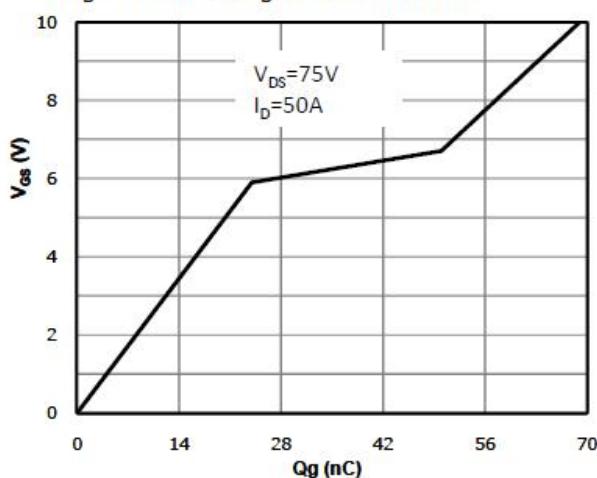


Fig 8: Body-diode Forward Characteristics

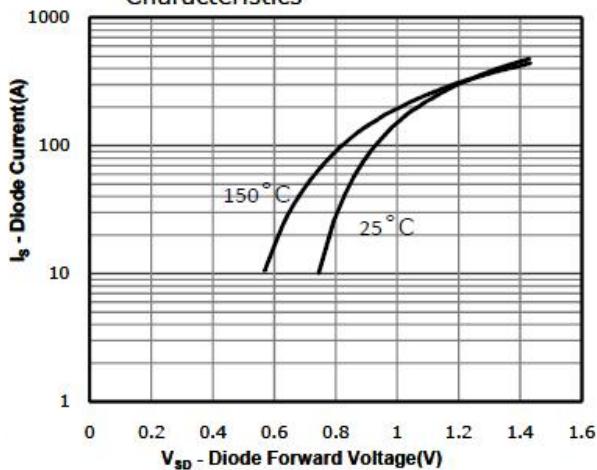


Fig 9: Power Dissipation

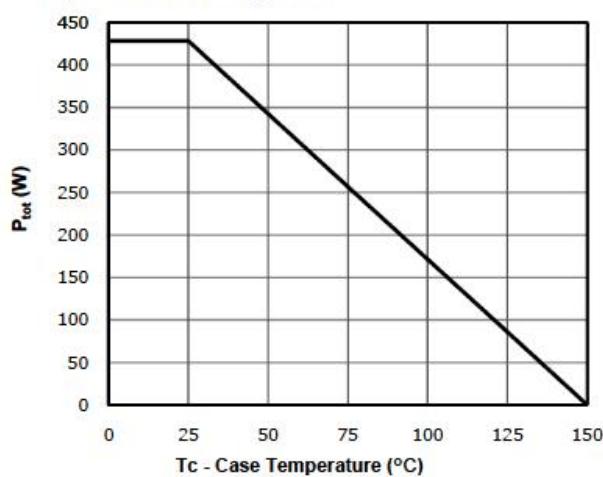


Fig 10: Drain Current Derating

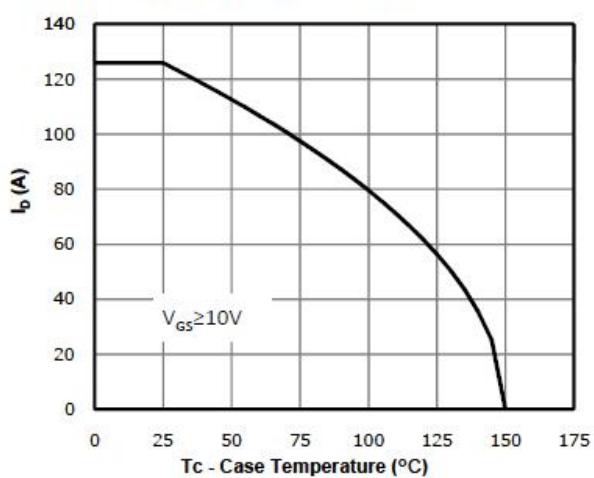


Fig 11: Safe Operating Area

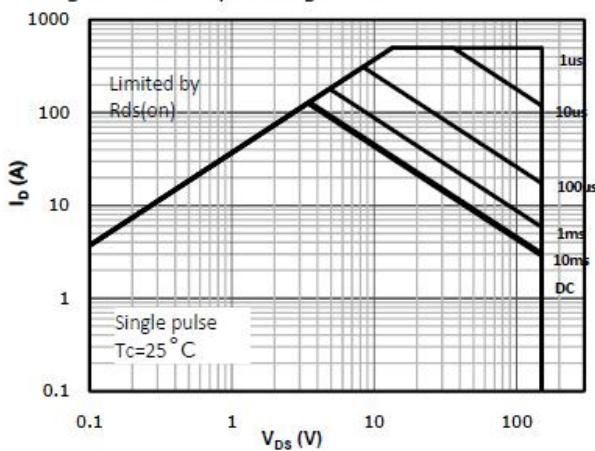
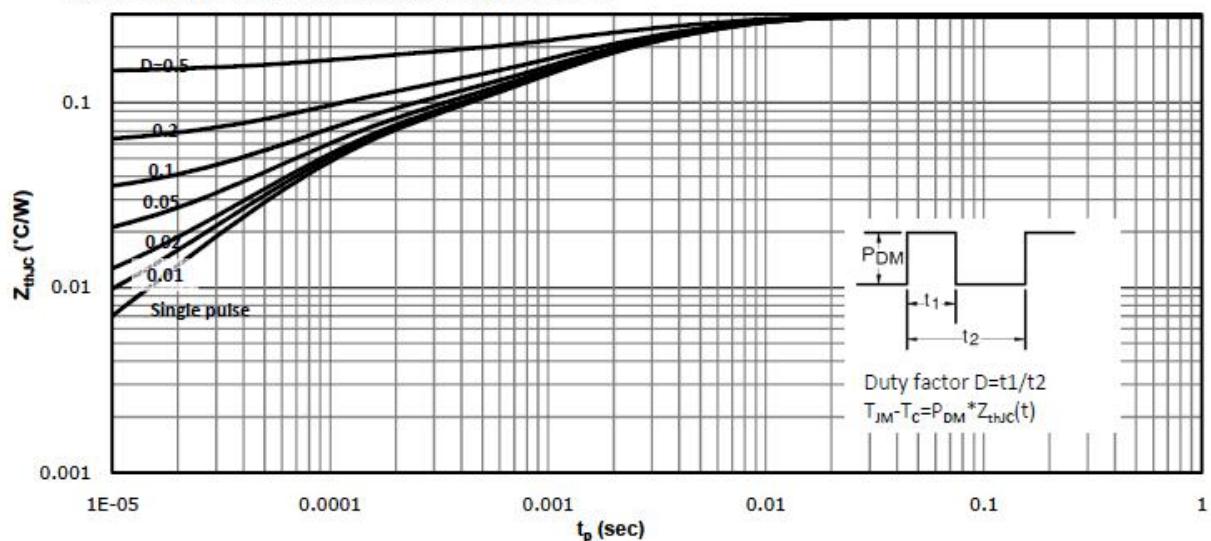


Fig 12: Max. Transient Thermal Impedance



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